

## 1) Fermi Functions

a) equilibrium and  $T > 0K$  @ fermi level

$$\hookrightarrow E = E_F$$

$$\therefore \frac{1}{1 + e^{E - E_F / kT}}$$

 $= \frac{1}{2}$  } the probability of an electronic state being occupied is 50%.
b)  $E_F = E_C$  ;  $E = E_C + kT$ 

$$\hookrightarrow E - E_F \Rightarrow (E_C + kT) - E_C = kT \quad \left. \vphantom{\frac{1}{1 + e^{kT/kT}}} \right\} \frac{1}{1 + e^{kT/kT}} = \frac{1}{e}$$

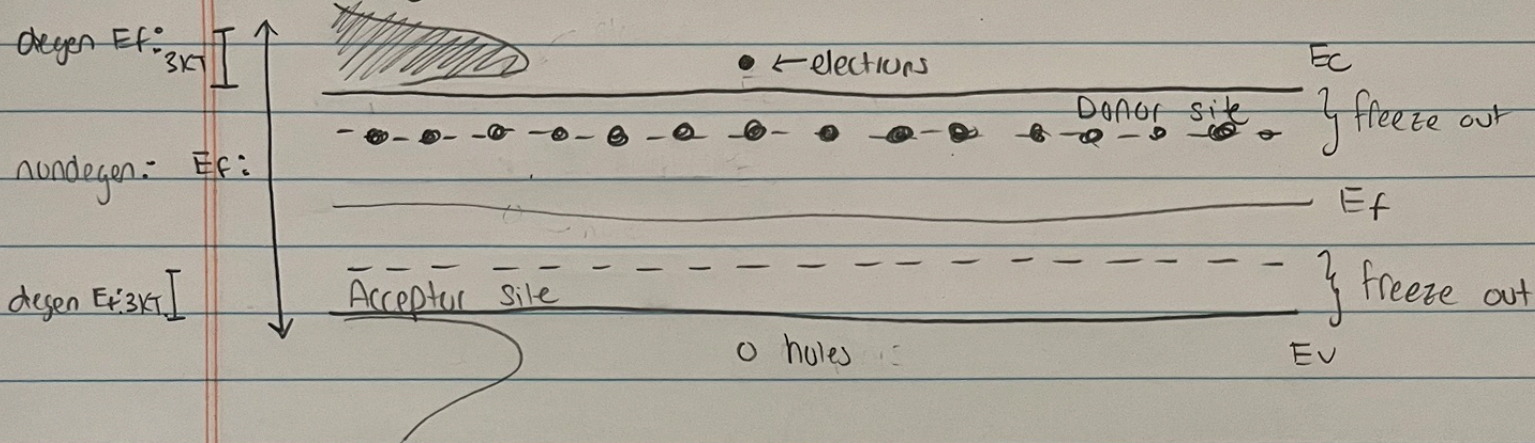
c)  $f(E_C + kT) = 1 - f(E_C + kT) \therefore f(E_C + kT) = 0.5 = 50\%$  $\hookrightarrow$  the fermi level is located at  $E_C + kT$ d)  $E = E_F - kT$ 

$$\hookrightarrow \text{hole probability} : 1 - \left( \frac{1}{1 + e^{E - E_F / kT}} \right)$$

$$\therefore 1 - \left( \frac{1}{1 + e^{-1}} \right) = 0.269$$



## 2) Energy Band Model - Pierret Problem 2.3



→ for intrinsic, n-type, p-type:  $E_f$  remains between the 2 bands in the middle

$E_f$ : for n-type is closer to  $E_c$   
p-type is closer to  $E_v$

## 3) Pierret 2.7: Prove the peak to be at $E_c + kT/2$ & $E_v - kT/2$

→ carrier distribution:  $\int_{E_c}^{E_{top}} g_c(E) f(E) dE \Rightarrow g_c(E) f(E)$   
of electrons

$$\text{Where } g_c(E) = \frac{m_n^* \sqrt{2m_n^*}}{n^2 \hbar^3} \cdot \frac{1}{1 + e^{(E - E_f)/kT}} = \frac{m_n^* \sqrt{2m_n^*}}{n^2 \hbar^3} \sqrt{E - E_c} e^{-\frac{(E - E_f)}{kT}}$$

$$\begin{aligned} \frac{d}{dE} (g_c(E) f(E)) &= 0 \text{ to get where the peak will occur} \\ &= \left( \frac{m_n^* \sqrt{2m_n^*}}{n^2 \hbar^3} \right) e^{-\frac{(E - E_f)}{kT}} - \left( \frac{m_n^* \sqrt{2m_n^*}}{n^2 \hbar^3} \right) \sqrt{E - E_c} e^{-\frac{(E - E_f)}{kT}} = 0 \end{aligned}$$

→ Solving this gives the peak to be at  $E = E_c + kT/2$



• Pierret → Problem 2.16

a) Uniformly doped p type  $\rightarrow N_A = 10^{15}/\text{cm}^3$  ; At  $T \approx 0\text{K}$

↳ equilibrium hole and electron concentration? w/  $T \approx 0\text{K}$ ,  $n$  &  $p$  will approach 0

b)  $N \gg n_i$  & all impurities are ionized ;  $n \approx N$  &  $p \approx n_i^2/N$

↳ Since  $N \gg n_i$  &  $n \approx N$ , we can say the impurity is a donor

c) Si @  $T \approx 300\text{K}$  ;  $n = 10^5/\text{cm}^3$

↳  $np = n_i^2$  &  $n = 10^5/\text{cm}^3 \rightarrow p = n_i^2 / n = (10^{10}/\text{cm}^3)^2 / 10^5/\text{cm}^3 = 10^{13}/\text{cm}^3$

↳ non-degenerate assumption

e)  $n_i = 10^{13}/\text{cm}^3$ ,  $n = 2p$ ,  $N_A = 0$  ;  $n$  &  $N_D = ?$

↳  $np = n_i^2$  where  $n = 2p \therefore n_i^2 = \frac{n^2}{2} \Rightarrow n = \sqrt{2} n_i$

Charge neutrality :  $p - n + N_D - N_A = 0$   
 $\frac{n}{2} - n + N_D - 0 = 0 \quad \left. \vphantom{\begin{matrix} p - n + N_D - N_A = 0 \\ \frac{n}{2} - n + N_D - 0 = 0 \end{matrix}} \right\} N_D = \frac{n}{2} = \frac{\sqrt{2} n_i}{2} = 0.707 \times 10^{13}/\text{cm}^3$

• Pierret → Problem 2.17

c)  $T = 300\text{K}$ ,  $N_A = 9 \times 10^{15}/\text{cm}^3$ ,  $N_D = 10^{16}/\text{cm}^3$

↳ (2.28) :  $n_i \gg |N_D - N_A| \therefore n \approx p \approx n_i \rightarrow n \approx n_i = N_D - N_A = 10^{15}/\text{cm}^3$

↳  $p = n_i^2 / (N_D - N_A) \approx (10^{10})^2 / 10^{15} = 10^5/\text{cm}^3$

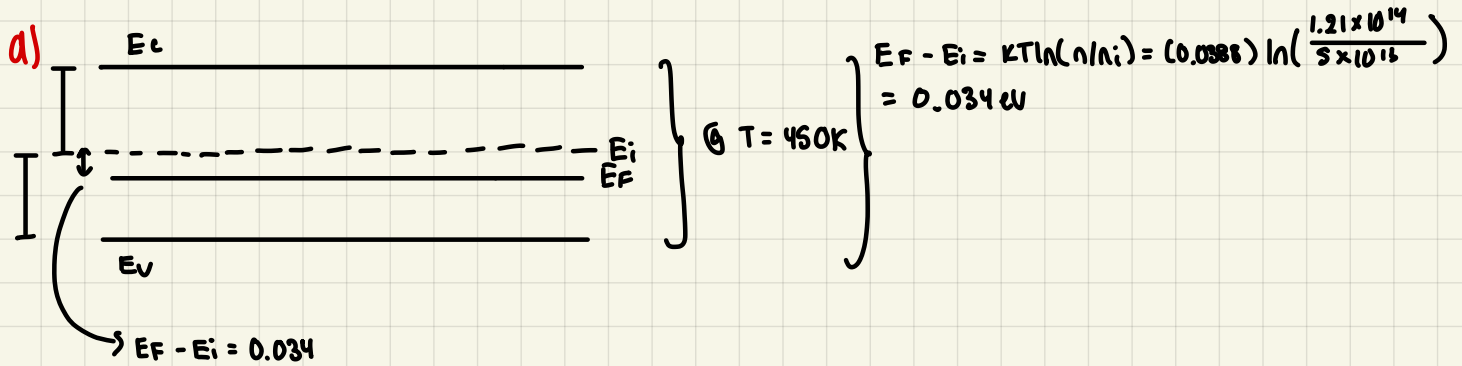
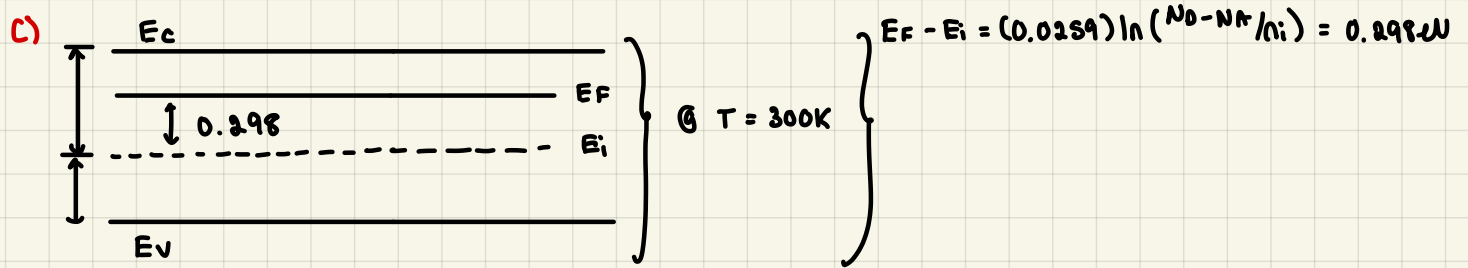
d)  $T = 450\text{K}$  ;  $N_A = 0$  ;  $N_D = 10^{14}/\text{cm}^3$

↳  $n_i(\text{Si}) \approx 5 \times 10^{13}/\text{cm}^3 \rightarrow n = \frac{N_D - N_A}{2} + \left[ \left( \frac{N_D - N_A}{2} \right)^2 + n_i^2 \right]^{1/2}$

$$n = \frac{10^{14}/\text{cm}^3}{2} + \left[ \left( \frac{10^{14}/\text{cm}^3}{2} \right)^2 + 5 \times 10^{13}/\text{cm}^3 \right]^{1/2} = 1.21 \times 10^{14}/\text{cm}^3$$

$$p = \frac{n_i^2}{n} \rightarrow \frac{(5 \times 10^{13}/\text{cm}^3)^2}{1.21 \times 10^{14}/\text{cm}^3} = 2.07 \times 10^{13}/\text{cm}^3$$

• Pierret → Problem 3.18



### • Activity 1

1. The 2 photon energies that an electron in the gnd state of a H atom can absorb are 12.1eV and 10.1eV
2. The shortest wavelength it can radiate is 99nm ~ 100nm

### • Activity 2

1. Bonding energy → As the hydrogen atoms get closer to each other, the energy exponentially decreases

Proton - Proton Repulsion Energy → As the hydrogen atoms grow closer, the repulsion energy exponentially increases

2. The bond length is determined by the shared energy levels, the size of the atoms, and etc.

### • Activity 3

1.  $3.41 \times 10^{20}$  energy states exist between 0.7eV and 0.72eV assuming the middle of the bandgap is at 0 energy
2.  $4.43 \times 10^{20}$  energy states exist between 0.8eV and 0.82eV assuming the middle of the bandgap is at 0 energy